

DOCKET NO: 245583US0S DIV

IN THE UNITED STATES PATENT & TRADEMARK OFFICE

IN RE APPLICATION OF :  
SATOSHI MATSUDA, ET AL. : ATTN: APPLICATION DIVISION  
SERIAL NO: NEW U.S. APPLN. :  
FILED: HEREWITH :  
FOR: SEMICONDUCTOR DEVICE :  
HAVING SILICIDE FILM AND  
MANUFACTURING METHOD  
THEREOF

PRELIMINARY AMENDMENT

COMMISSIONER FOR PATENTS  
ALEXANDRIA, VIRGINIA 22313

SIR:

Prior to examination on the merits, please amend the above-identified Divisional application of U.S. Application Serial No. 10/241,488, filed on September 12, 2002, now allowed, as follows.

**Amendments to the Specification** begin on page 2 of this paper.

**Amendments to the Claims** are reflected in the listing of claims which begins on page 3 of this paper.

**Remarks/Arguments** begin on page 6 of this paper.